

# Standard Rectifier Module

**V<sub>RRM</sub>** = 2x2200 V

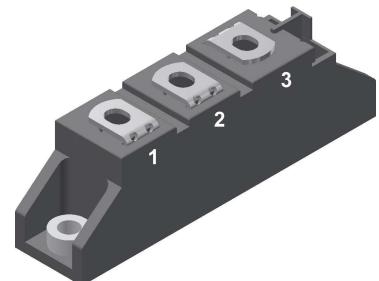
**I<sub>FAV</sub>** = 120 A

**V<sub>F</sub>** = 1.13 V

## Phase leg

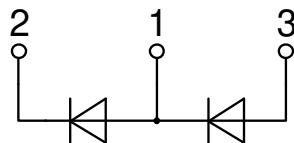
### Part number

**MDD95-22N1B**



Backside: isolated

 E72873



### Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

### Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Package: TO-240AA

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Height: 30 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

### Disclaimer Notice

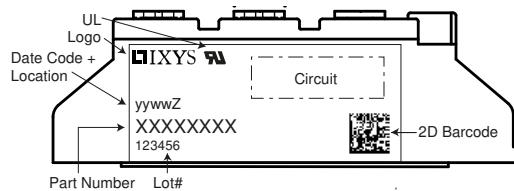
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**Rectifier**

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$V_{RSM}$	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			2300	V
$V_{RRM}$	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			2200	V
$I_R$	reverse current	$V_R = 2200 \text{ V}$ $V_R = 2200 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		200 15	$\mu\text{A}$ mA
$V_F$	forward voltage drop	$I_F = 150 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$		1.20	V
		$I_F = 300 \text{ A}$			1.43	V
		$I_F = 150 \text{ A}$	$T_{VJ} = 125^\circ\text{C}$		1.13	V
		$I_F = 300 \text{ A}$			1.46	V
$I_{FAV}$	average forward current	$T_C = 100^\circ\text{C}$	$T_{VJ} = 150^\circ\text{C}$		120	A
$I_{F(\text{RMS})}$	RMS forward current	180° sine			180	A
$V_{F0}$	threshold voltage	$\left. \begin{array}{l} \text{slope resistance} \\ \end{array} \right\} \text{for power loss calculation only}$	$T_{VJ} = 150^\circ\text{C}$		0.75	V
$r_F$	slope resistance				1.95	$\text{m}\Omega$
$R_{\text{thJC}}$	thermal resistance junction to case				0.26	K/W
$R_{\text{thCH}}$	thermal resistance case to heatsink			0.2		K/W
$P_{\text{tot}}$	total power dissipation	$T_C = 25^\circ\text{C}$			481	W
$I_{FSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ\text{C}$		2.80	kA
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		3.03	kA
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 150^\circ\text{C}$		2.38	kA
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		2.57	kA
$I^2t$	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ\text{C}$		39.2	$\text{kA}^2\text{s}$
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		38.1	$\text{kA}^2\text{s}$
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 150^\circ\text{C}$		28.3	$\text{kA}^2\text{s}$
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		27.5	$\text{kA}^2\text{s}$
$C_J$	junction capacitance	$V_R = 400 \text{ V}; f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$	116		pF

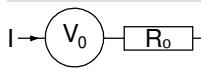
**Package TO-240AA**

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$I_{RMS}$	RMS current	per terminal			200	A
$T_{VJ}$	virtual junction temperature		-40		150	°C
$T_{op}$	operation temperature		-40		125	°C
$T_{stg}$	storage temperature		-40		125	°C
<b>Weight</b>				76		g
$M_D$	mounting torque		2.5		4	Nm
$M_T$	terminal torque		2.5		4	Nm
$d_{Spp/App}$	creepage distance on surface / striking distance through air	terminal to terminal	13.0	9.7		mm
$d_{Spb/Apb}$		terminal to backside	16.0	16.0		mm
$V_{ISOL}$	isolation voltage	t = 1 second t = 1 minute 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	4800			V
			4000			V



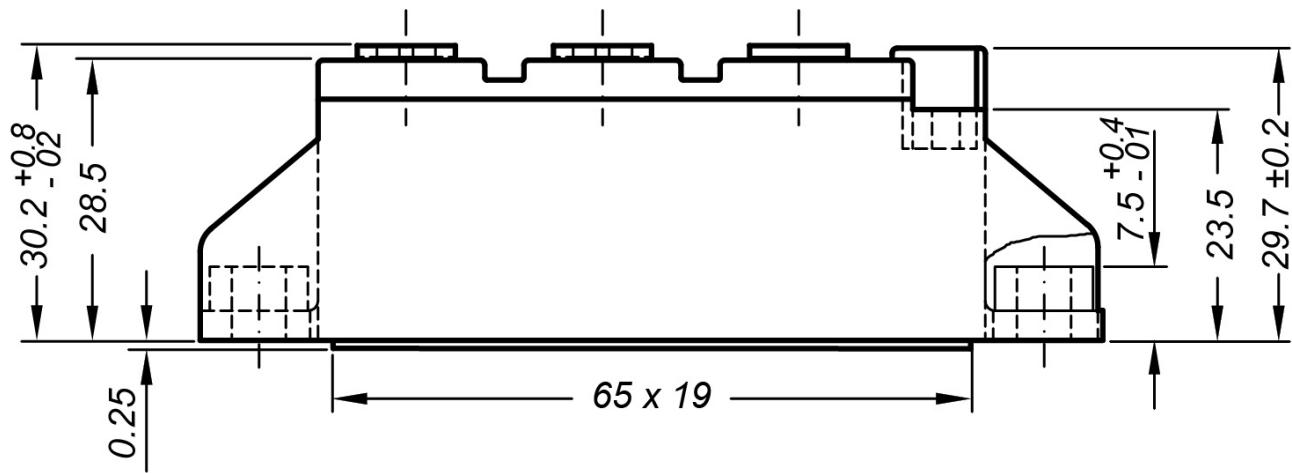
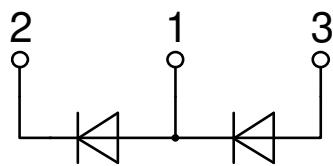
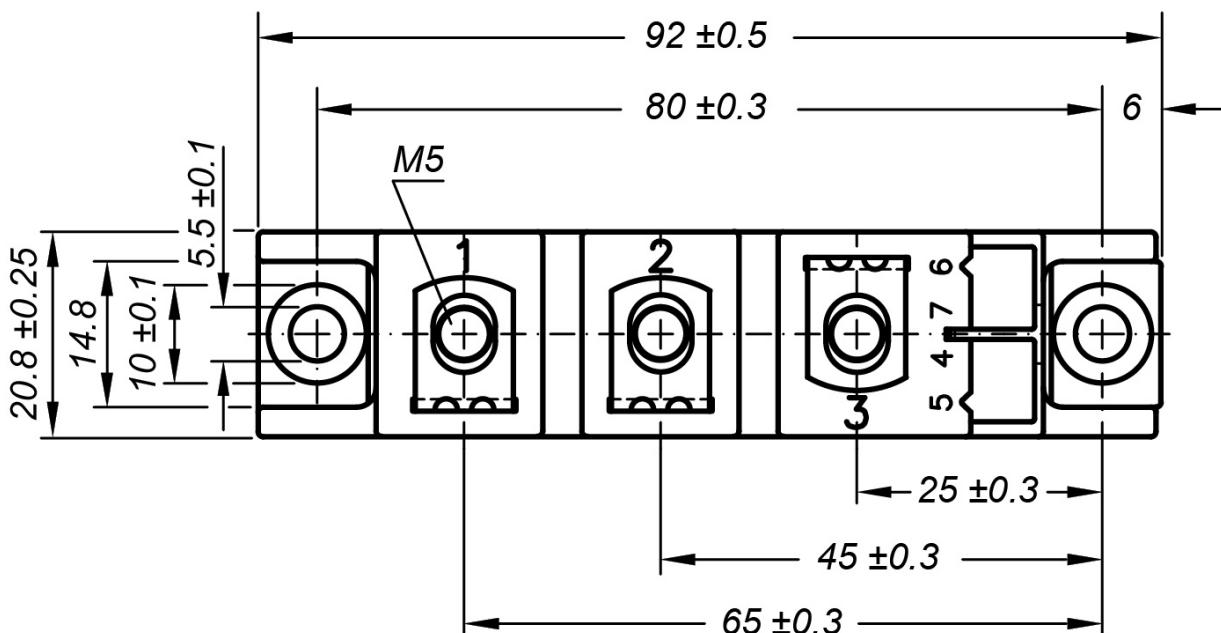
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MDD95-22N1B	MDD95-22N1B	Box	36	470236

**Equivalent Circuits for Simulation**
<sup>\*</sup>on die level

 $T_{VJ} = 150^\circ\text{C}$ 

**Rectifier**
 $V_{0\max}$  threshold voltage 0.75  
 $R_{0\max}$  slope resistance \* 0.76

V

mΩ

**Outlines TO-240AA**

*General tolerance: DIN ISO 2768 class „c“*


## Rectifier

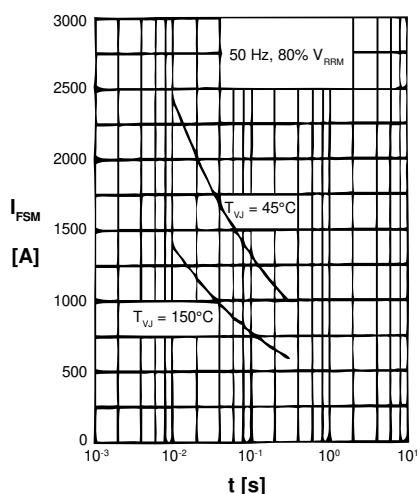


Fig. 1 Surge overload current  
 $I_{TSM}, I_{FSM}$ : Crest value,  $t$ : duration

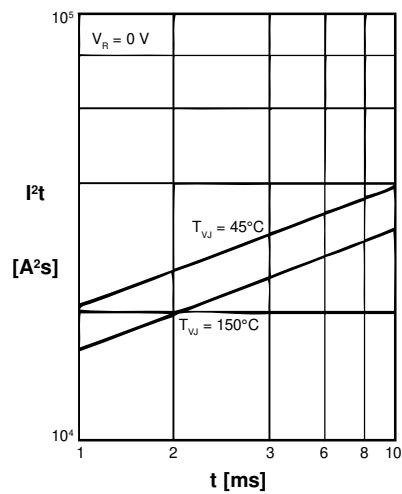


Fig. 2  $I^2t$  versus time (1-10 ms)

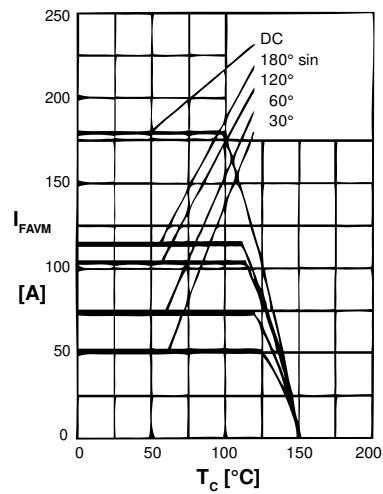


Fig. 3 Maximum forward current  
at case temperature

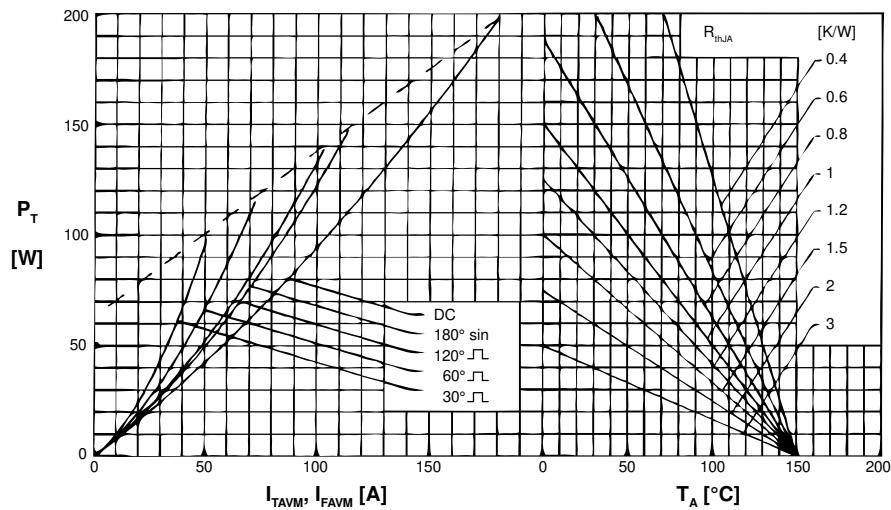


Fig. 4 Power dissipation vs. onstate current and ambient temperature (per diode)

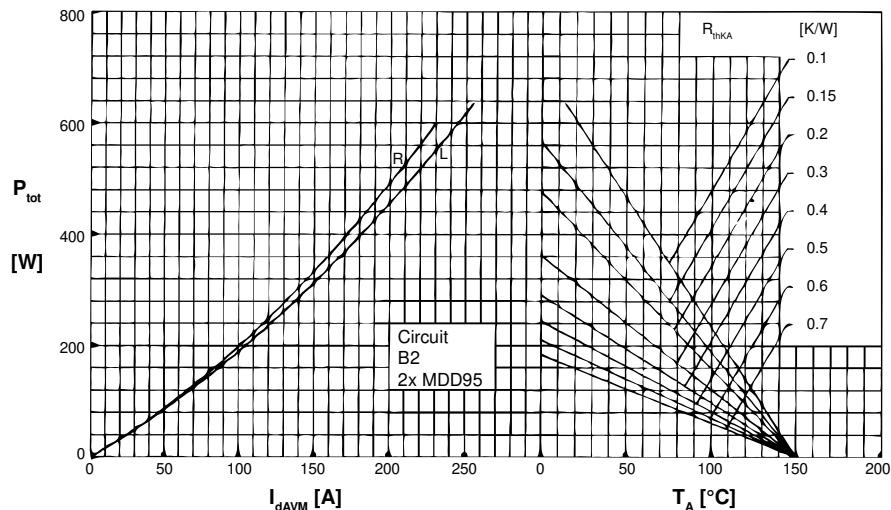


Fig. 6 Single phase rectifier bridge: Power dissipation versus direct output current  
and ambient temperature;  $R$  = resistive load,  $L$  = inductive load

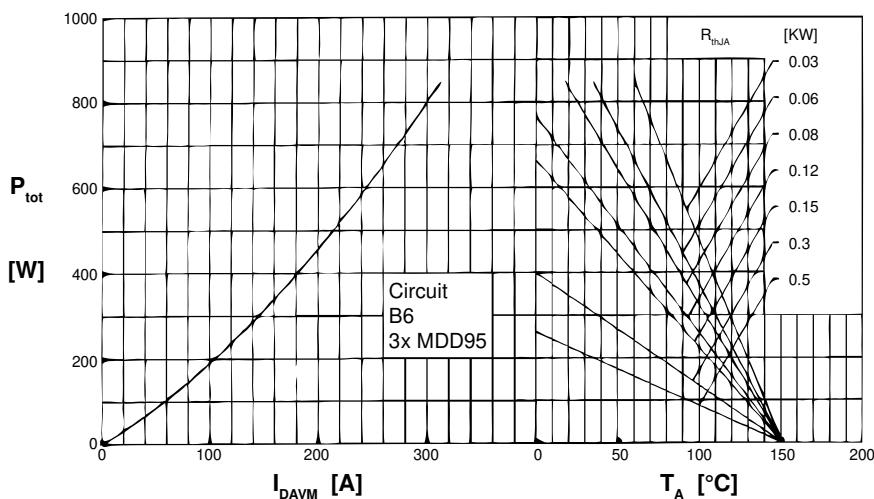
**Rectifier**


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

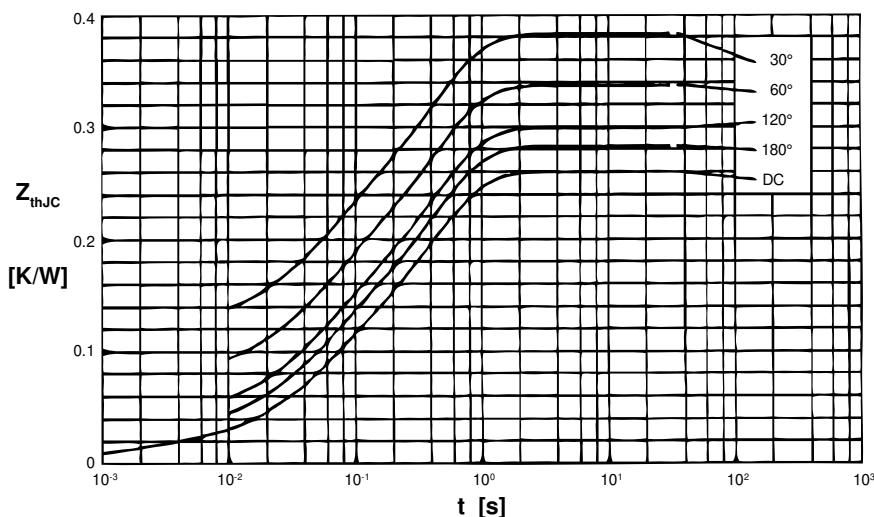


Fig. 7 Transient thermal impedance junction to case (per diode)

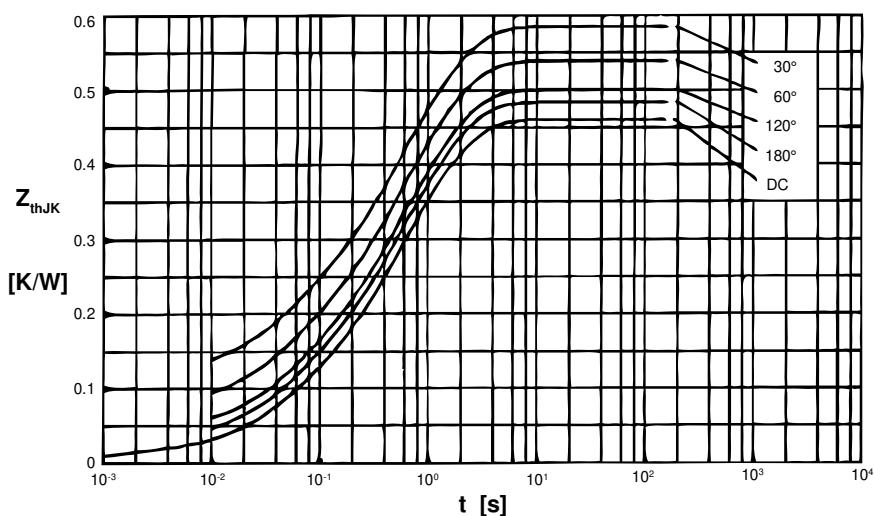


Fig. 8 Transient thermal impedance junction to heatsink (per thyristor)

$R_{thJC}$  for various conduction angles d:

d	$R_{thJC}$ [K/W]
DC	0.26
180°	0.28
120°	0.30
60°	0.34
30°	0.38

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ [K/W]	$t_i$ [s]
1	0.013	0.0012
2	0.072	0.0470
3	0.175	0.3940

$R_{thJK}$  for various conduction angles d:

d	$R_{thJK}$ [K/W]
DC	0.46
180°	0.48
120°	0.50
60°	0.54
30°	0.58

Constants for  $Z_{thJK}$  calculation:

i	$R_{thi}$ [K/W]	$t_i$ [s]
1	0.013	0.0012
2	0.072	0.0470
3	0.175	0.3940
4	0.200	1.3200